

PNP -1.5A -30V Middle Power Transistor

Parameter	Value
$V_{\sf CEO}$	-30V
I _C	-1.5A

Features

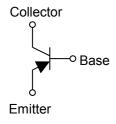
- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SD2662
- 3) Low V_{CE(sat)}

$$V_{CE(sat)} = -0.37V(Max.)$$

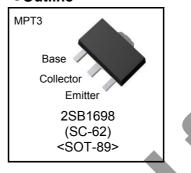
 $(I_C/I_B = -1A/-50mA)$

4) Lead Free/RoHS Compliant.

•Inner circuit



Outline



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SB1698	MPT3	4540	T100	180	12	1,000	FL

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	-30	V
Collector-emitter voltage		V _{CEO}	-30	V
Emitter-base voltage		V_{EBO}	-6	V
Collector current	DC	I _C	-1.5	Α
	Pulsed	I _{CP} *1	-3	A
Power dissipation		P _D *2	0.5	W
		P _D *3	2.0	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	∕-55 to +150	°C

^{*1} Pw=1ms, single pulse

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C =-1mA	-30	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = -10μA	-30	ı	ı	V
Emitter-base breakdown voltage	BV _{EBO}	$I_E = -10\mu A$	-6	ı	ı	V
Collector cut-off current	I _{CBO}	$V_{CB} = -30V$	-	ı	-100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -6V	-	ı	-100	nA
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = -1A, I_{\rm B} = -50 \text{mA}$	-	-200	-370	mV
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	270	ı	680	-
Transition frequency	f _T	$V_{CE} = -2V$, $I_{E} = 100$ mA f=100MH _Z	-	280	ı	MHz
Output capacitance	C_{ob}	$V_{CB} = -10V$, $I_E = 0A$ f = 1MHz	-	13	-	pF

^{*2} Each terminal mounted on a reference land

^{*3} Mounted on a ceramic board (40×40×0.7 mm)

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

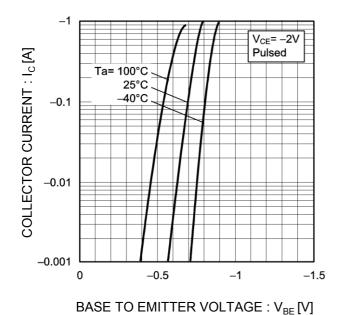
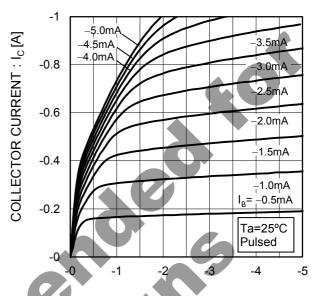


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : $V_{CE}[V]$

Fig.3 DC Current Gain vs. Collector Current(I)

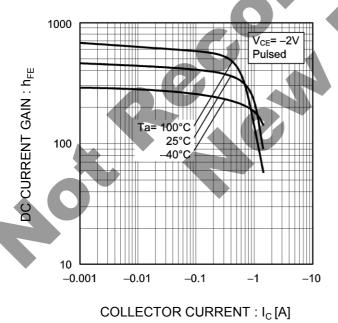
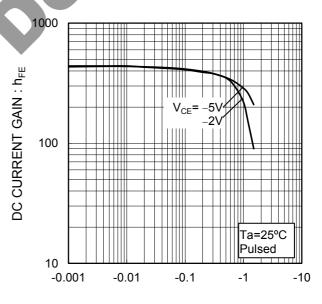


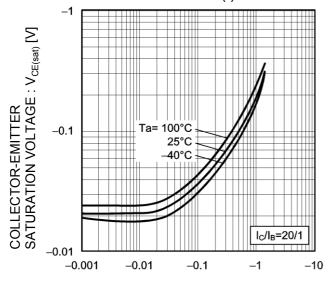
Fig.4 DC Current Gain vs. Collector Current(II)



COLLECTOR CURRENT : I_C[A]

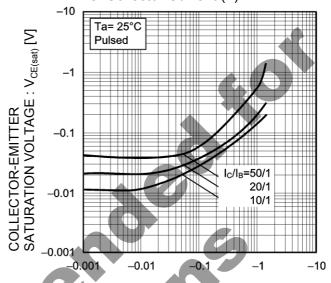
●Electrical characteristic curves(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (I)



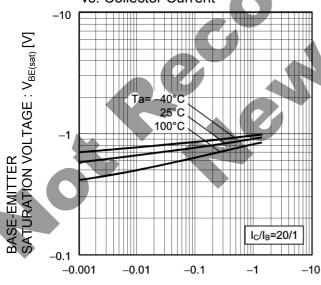
COLLECTOR CURRENT : I_C[A]

Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II)



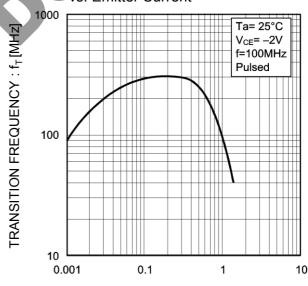
COLLECTOR CURRENT : Ic [A]

Fig.7 Base-Emitter Saturation Voltage vs. Collector Current



COLLECTOR CURRENT : $I_C[A]$

Fig.8 Gain Bandwidth Product vs. Emitter Current



EMITTER CURRENT :I_F [A]

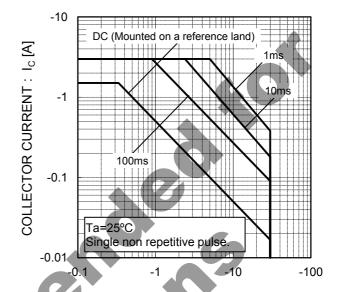
●Electrical characteristic curves(Ta = 25°C)

Fig.9 Emitter input capacitance vs. **Emitter-Base Voltage** Collector output capacitance vs. COLLECTOR OUTPUT CAPACITANCE: Cob [pF] EMITTER INPUT CAPACITANCE: Cib [pF] Collector-Base Voltage 1000 Ta= 25°C f=1MHz I_C=0A C_{ib} 100 10

COLLECTOR - BASE VOLTAGE : V_{CB} [V] EMITTER - BASE VOLTAGE : VEB [V]

-0.1

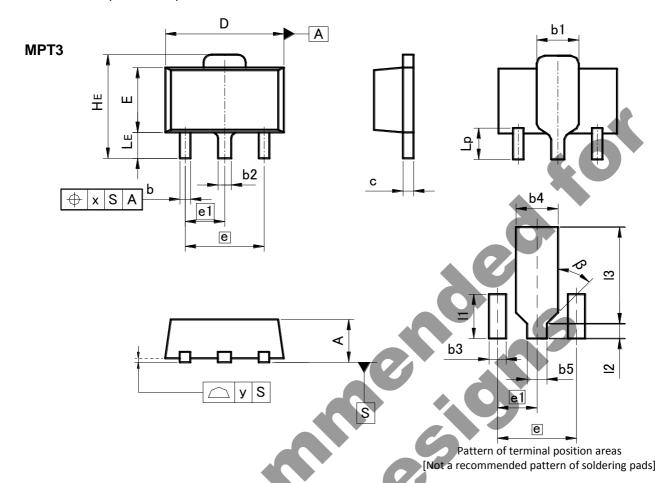
Fig. 10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE : V_{CE} [V]



●Dimensions (Unit: mm)



DIM	MILIM	ETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
Α	1.40	1.50	0.055	0.059
b	0.30	0.50	0.012	0.020
b1	1.50	1.70	0.059	0.067
b2	0.40	0.60	0.016	0.024
C	0.35	0.50	0.014	0.020
D	4.40	4.70	0.173	0.185
E	2.40	2.70	0.094	0.106
е	3.0	00	0.1	18
e1	1.	50	0.0)59
HE	3.70	4.30	0.146	0.169
LE	0.80	1.20	0.031	0.047
Lp	1.01	1.41	0.040	0.056
Х		0.15	_	0.006
У	-	0.10	- 1	0.004

DIM	MILIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
b3	_	0.65	-	0.026	
b4	_	1.70	-	0.067	
b5	_	0.75	-	0.030	
11	_	1.71	1	0.067	
12	_	0.58	1	0.023	
13	_	3.72	_	0.146	
β	45°		45°		

Dimension in mm / inches

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